AiT Semiconductor Inc. BC856W_BC857W_BC858W

TRANSISTOR

PNP PLASTIC-ENCAPSULATE TRANSISTOR

DESCRIPTION

The BC856W, BC857W and BC858W are available in the SOT-323 package.

www.ait-ic.com

ORDERING INFORMATION

| Package Type | Part Number | | |
|--|---------------|--|--|
| SOT-323 | BC856AW | | |
| | BC856BW | | |
| | BC857AW | | |
| | BC857BW | | |
| | BC857CW | | |
| | BC858AW | | |
| | BC858BW | | |
| | BC858CW | | |
| SPQ | 3,000pcs/Reel | | |
| AiT provides all RoHS Compliant Products | | | |

ABSOLUTE MAXIMUM RATINGS

 $T_A = 25^{\circ}C$, unless otherwise specified.

| Parameter | | Value | | |
|--|--------|---------------|--|--|
| V _{CBO,} Collector-Bas e Voltage | BC856W | -80 V | | |
| | BC857W | -50 V | | |
| | BC858W | -30 V | | |
| V _{CEO} , Collector-Emitter Voltage | BC856W | -65 V | | |
| | BC857W | -45 V | | |
| | BC858W | -30 V | | |
| V _{EBO} , Emitter-Base Voltage | | -5 V | | |
| Ic, Collector Current-Continuous | | -0.1 A | | |
| P _c , Collector Power Dissipation | | 150 mW | | |
| T _J , Junction Temperature | | 150 °C | | |
| T _{stg,} Storage Temperature | | -65 ~ +150 °C | | |

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

FEATURE

- Low current (max. -100 mA)
- Low voltage (max. -65 V)

APPLICATION

- Ideally suited for automatic insertion.
- For switching and AF amplifier application.

PIN DESCRIPTION



| PIN# | DESCRIPTION | | |
|------|-------------|--|--|
| 1 | Base | | |
| 2 | Emitter | | |
| 3 | Collector | | |



ELECTRICAL CHARACTERISTICS

 $T_A=25^{\circ}C$ unless otherwise specified.

| Parameter | Symbol | Condition | | Min. | Max. | Unit | |
|---|-----------------------|---|------------------|--------|-------|------|---|
| Collector-Base Breakdown Voltage | V _{СВО} | I _C = -10 μΑ, I _E = 0 | | BC856W | -80 | - | V |
| | | | | BC857W | -50 | - | |
| Voltage | | | | BS858W | -30 | - | |
| Collector-Emitter Breakdown Voltage | Vceo | I _C = -10 mA, I _B = 0 | | BC856W | -65 | - | |
| | | | | BC857W | -45 | - | V |
| | | | | BS858W | -30 | - | |
| Collector-Base Breakdown Voltage | Vebo | I _E = -1 μA, I _C = 0 | | -5 | - | V | |
| DC Current Gain | h _{FE} | V _{CE} =-5V , I _C =-2mA | BC856AW~BC858AW | | 125 | 250 | |
| | | | BC856BW~BC858BW | | 220 | 475 | |
| | | | BC857CW, BC858CW | | 420 | 800 | |
| Collector Cut-off Current | Ісво | $V_{CB} = -30 \text{ V}, \text{ I}_{E} = 0$ | | - | -15 | nA | |
| Collector-Emitter Saturation Voltage | V _{CE} (sat) | I _C = -100 mA, I _B = -5 mA | | - | -0.65 | V | |
| Base-Emitter Saturation Voltage | V _{BE} (sat) | I _C = -100 mA, I _B = -5 mA | | - | -1.1 | V | |
| Transition Frequency | f⊤ | V _{CE} = -5 V, I _C = -10 mA, f = 100 MHz | | 100 | - | MHz | |
| Collector Capacitance | C _{ob} | V _{CB} = -10 V, f = 1 MHz | | - | 4.5 | pF | |



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TYPICAL CHARACTERISTICS

Fig 1. Static Characteristic

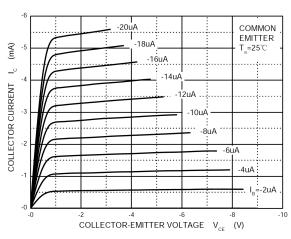
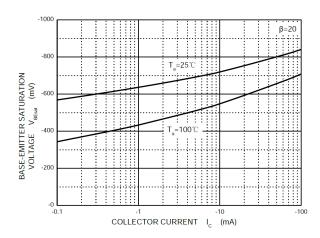
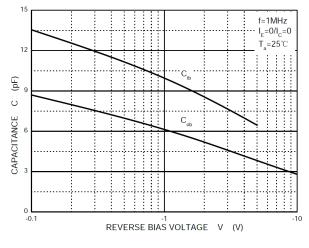


Fig 3. V_{BE (sat)} - I_C







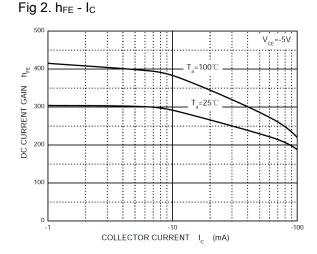
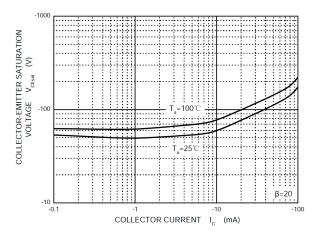
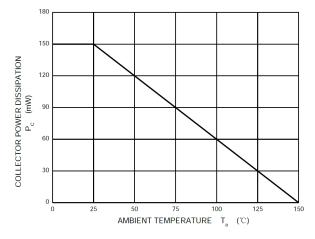


Fig 4. V_{CE (sat)} - I_C





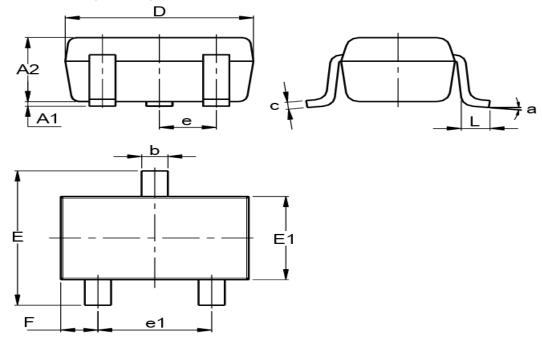


REV1.0 - JAN 2024 RELEASED -



PACKAGE INFORMATION

Dimension in SOT-323 (Unit: mm)



| Currence al | Millimeter | | |
|-------------|------------|-------|--|
| Symbol | Min. | Max. | |
| A1 | 0.000 | 0.100 | |
| A2 | 0.800 | 1.000 | |
| b | 0.200 | 0.400 | |
| с | 0.080 | 0.180 | |
| D | 1.000 | 2.220 | |
| E | 2.000 | 2.450 | |
| E1 | 1.150 | 1.350 | |
| е | 0.650 TYP. | | |
| e1 | 1.200 | 1.400 | |
| F | 0.250 | 0.475 | |
| L | 0.250 | 0.460 | |
| а | 0° | 8° | |



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